

Patent Attorney's Docket No. <u>015290-457</u>

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of

Jerome S. HUBACEK et al.

Application No.: 09/749,916

Filed: December 29, 2000

For: ELECTRODE FOR PLASMA
PROCESSES AND METHOD FOR
MANUFACTURE AND USE THEREOF

AMENDMENT AFTER FINAL REJECTION

Assistant Commissioner for Patents Washington, D.C. 20231

Sir:

In response to the final Official Action dated September 23, 2002, please amend the above-identified application as follows:

IN THE CLAIMS:

Please cancel Claims 2, 22, 24 and 26 without prejudice to or disclaimer of the subject matter therein.

Please replace Claims 1, 3, 10, 23, 27 and 30 as follows:

1. (Amended) A low resistivity silicon electrode adapted to be mounted in a plasma reaction chamber used in semiconductor substrate processing, comprising:

a silicon electrode comprising a showerhead electrode having a plurality of gas outlets arranged to distribute process gas in the plasma reaction chamber during use of the showerhead electrode, the electrode having a thickness of about 0.3 inch to 0.5 inch and an electrical resistivity of less than 1 ohm-cm, the electrode having an RF driven or

De not Liter